



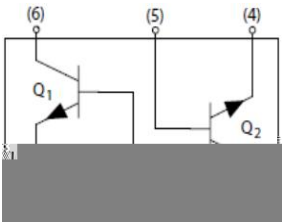
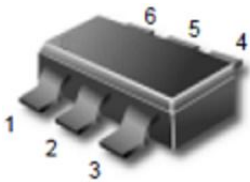
	! " #	\$! % & '	! () % * +	, -	. /
A	2016-5				
B	2019-4-20		0 1 2 3 4) 5 6 7 8 9 :	; < =	> ? @
C	2021-4-20	1	A B C D E F G 3 4 H I F G J K L M	N O P	> ? @
D	2021-10-16	4	Q R S T U V :	W X	> ? @



SOT-363 Y Z Z 2 [NPN \] ^ _ ` a M
Double silicon NPN transistor in a SOT-363 Plastic Package.

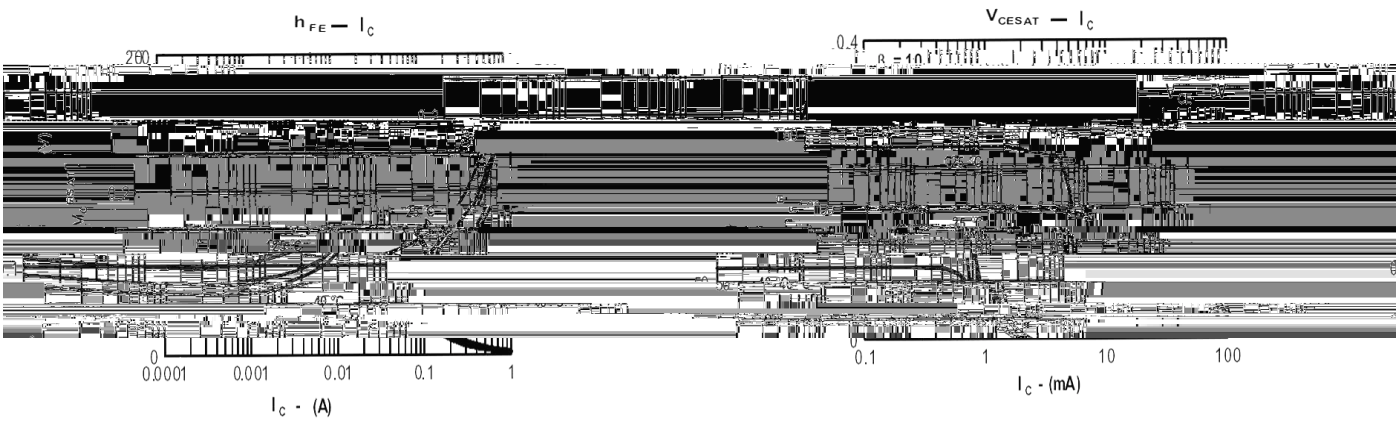
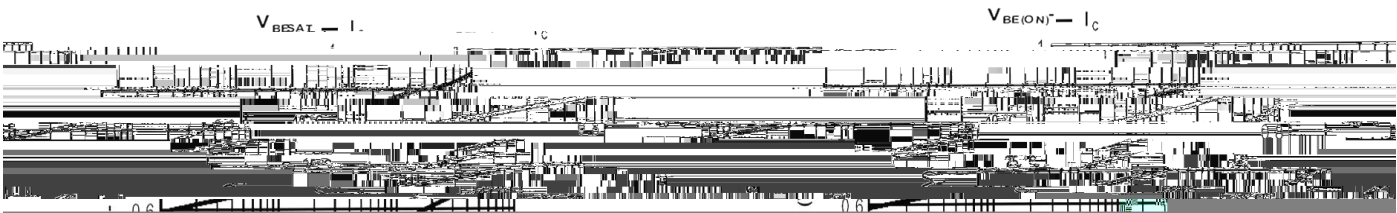
b c d e f ,g h MMDT5401 i j M F G k l M
High voltage, complementary pair with MMDT5401. HF Product.

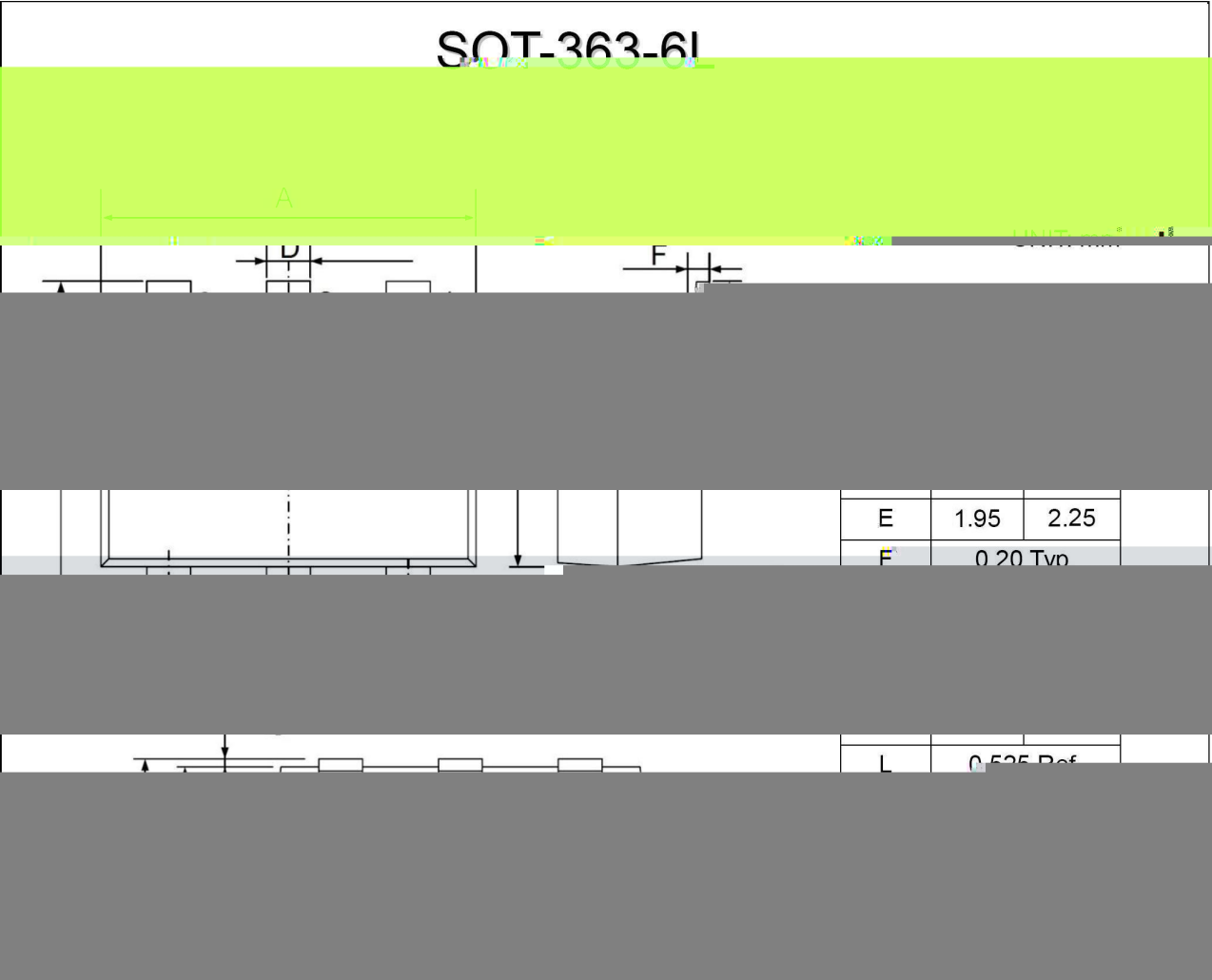
m n o p f e q r M
General purpose high voltage amplifier.



PIN1 s 4 t Emitter PIN 2 s 5 t Base PIN 3 s 6 t Collector

See Marking Instructions.







G 1 *

¥ | t

● t § " 1 © a

G1 t § □ x « '

***: § ¬ k - x « ' H ® ¬ k - x ¯ °

Note:

● t " 1 " Pin

G1 t Product Type Code

***: Lot No. Code, code change with Lot No.



5 **Temperature Profile for IR Reflow Soldering(Pb-Free)**

- 1

150 180

60 90sec;
- 2

245±5

5±0.5sec;
- 3

2 10°C/sec.
- Note:

1.Preheating:150~180°C, Time:60~90sec.

2.Peak Temp.:245±5°C, Duration:5±0.5sec.

3. Cooling Speed: 2~10°C/sec.

t